



DESCRIPTION

The AP63201 is a 2A, synchronous buck converter with a wide input voltage range of 3.8V to 32V and fully integrates a $125m\Omega$ high-side power MOSFET and a $68m\Omega$ low-side power MOSFET to provide high-efficiency step-down DC-DC conversion.

The AP63201 device is used by minimizing the external component count due to its adoption of peak current mode control along with its integrated compensation network.

The AP63201 is optimized for Electromagnetic Interference (EMI) reduction. The converter features

Frequency Spread Spectrum (FSS) with a switching frequency jitter of ±6%, which reduces EMI by not allowing emitted energy to stay in any one frequency for a significant period of time. It also has a proprietary gate driver scheme to resist switching node ringing without sacrificing MOSFET turn-on and turn-off times, further reducing high-frequency radiated EMI noise caused by MOSFET switching.

The device is available in the low-profile, TSOT26 package.

FEATURES

- VIN 3.8V to 32V
- 2A Continuous Output Current
- 0.8V ± 1% Reference Voltage
- 22µA Ultralow Quiescent Current (Pulse Frequency Modulation)
- 500kHz Switching Frequency
- Supports Pulse Width Modulation (PWM)
- Proprietary Gate Driver Design for Best EMI Reduction
- Frequency Spread Spectrum (FSS) to Reduce EMI

- Low-Dropout (LDO) Mode
- Precision Enable Threshold to Adjust UVLO
- Protection Circuitry
 - Undervoltage Lockout (UVLO)
 - Cycle-by-Cycle Peak
 Current Limit
 - Thermal Shutdown



APPLICATIONS

- 12V and 24V Distributed Power Bus Supplies
- Flat Screen TV Sets and Monitors
- Power Tools and Laser Printers
- White Goods and Small Home Appliances
- FPGA, DSP, and ASIC Supplies
- Home Audio
- Network Systems
- Set Top Boxes
- Gaming Consoles
- Consumer Electronics

FUNCTIONAL BLOCK

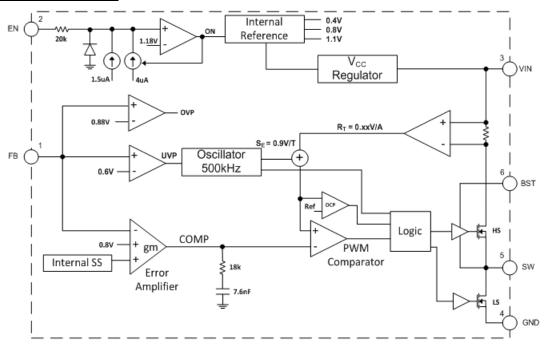


Figure 1. Functional Block Diagram



ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Rating	Unit	
VIN	Supply Voltage	-0.3 to +35.0 (DC)	V	
VIIN	Supply Voltage	-0.3 to +40.0 (400ms)	V	
V _{sw}	Switch Node Voltage	-1.0 to VIN + 0.3 (DC)	V	
V SW	Switch Node Voltage	-2.5 to VIN + 2.0 (20ns)	V	
V _{BST}	Bootstrap Voltage	V _{SW} - 0.3 to V _{SW} + 6.0	V	
V_{FB}	Feedback Voltage	-0.3 to +6.0	V	
V _{EN}	Enable/UVLO Voltage	-0.3 to +35.0	V	
T _{ST}	Storage Temperature	-65 to +150	°C	
TJ	Junction Temperature	+150	°C	
T∟	Lead Temperature	+260	°C	
ESD Susceptib	ility	<u>.</u>		
HBM	Human Body Mode	2000	V	
CDM	Charge Device Model	1000	V	

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Min	Max	Unit
VIN	Supply Voltage	3.8	32	V
T _A	Operating Ambient Temperature Range	-40	+85	°C
Τ _J	Operating Junction Temperature Range	-40	+125	°C



EVALUATION BOARD



Figure 2. AP63201WU-EVM

QUICK START GUIDE

The AP63201WU-EVM has a simple layout and allows access to the appropriate signals through test points. To evaluate the performance of the AP63201WU, follow the procedure below:

- 1. For evaluation board configured at V_{OUT}=5V, connect a power supply to the input terminals V_{IN} and GND. Set V_{IN} to 12V.
- 2. Connect the positive terminal of the electronic load to Vout and negative terminal to GND.
- 3. For Enable, place a jumper to "H" position to enable IC. Jump to "L" position to disable IC.
- 4. The evaluation board should now power up with a 5V output voltage.
- 5. Check for the proper output voltage of 5V (±1%) at the output terminals VouT and GND. Measurement can also be done with a multimeter with the positive and negative leads between VouT and GND.
- 6. Set the load to 2A through the electronic load. Check for the stable operation of the SW signal on the oscilloscope. Measure the switching frequency.



MEASUREMENT/PERFORMANCE GUIDELINES:

- When measuring the output voltage ripple, maintain the shortest possible ground lengths on the oscilloscope probe. Long ground leads can erroneously inject high frequency noise into the measured ripple.
- 2) For efficiency measurements, connect an ammeter in series with the input supply to measure the input current. Connect an electronic load to the output for output current.

SETTING OUTPUT VOLTAGE:

(1) Setting the output voltage

The AP63201WU features external programmable output voltage by using a resistor divider network R3 and R1 as shown in the typical application circuit. The output voltage is calculated as below,

$$V_{OUT} = 0.8 \times \left(\frac{R_1 + R_3}{R_1}\right)$$

First, select a value for R1 according to the value recommended in the table 1. Then, R3 is determined. The output voltage is given by Table 1 for reference. For accurate output voltage, 1% tolerance is required.

V _{out}	R3	R1	C4	C6-C8
1.8V	77.5 KΩ	62 KΩ	100pF	22uFx2
2.5V	131 ΚΩ	62 KΩ	100pF	22uFx2
3.3V	182 KΩ	62 KΩ	100 pF	22uFx2
5V	157 KΩ	30 ΚΩ	100 pF	22uFx2
12V	249 ΚΩ	18 KΩ	56 pF	22uFx4

Table 1. Resistor selection for output voltage setting

(2) Output feed-forward capacitor selection

The AP63201WU has the internal integrated loop compensation as shown in the function block diagram. The compensation network includes an 18k resistor and a 7.6nF capacitor. Usually, the type II compensation network has a phase margin between 60 and 90 degrees. However, if the output capacitor has ultra-low ESR, the converter results in low phase margin. To increase the converter phase margin, a feed-forward cap C4 is used to boost the phase margin at the converter crossover frequency, $f_{\mathcal{C}}$. The feed-forward capacitor is given by Table 1 for reference. The feed-forward capacitor is calculated as below,



$$C_4 = \frac{1}{2\pi \times f_C \times R_3}$$

Table 2 shows a list of recommended inductors for common output voltages.

V _{OUT}	1.8V	2.5V	3.3V	5.0V	12V
Inductor	3.3µH	3.3µH	6.8µH	10μH	15µH
Wurth Part	744 393 440 33	744 393 440 33	744 393 460 68	744 393 461 00	744 770 915 0

Table 2. Recommended Inductors

EVALUATION BOARD SCHEMATIC

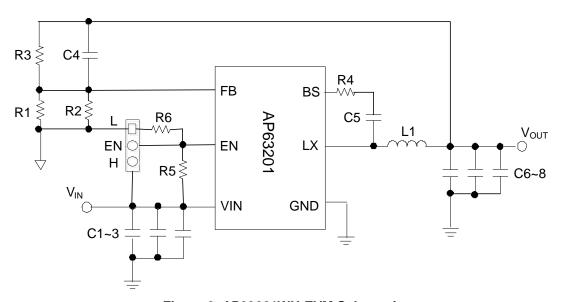


Figure 3. AP63201WU-EVM Schematic

BILL OF MATERIALS for AP63201WU-EVM (Vout=5V)

Item	Value	Туре	Rating	Description	Description
C2	10μF	X5R/X7R, Ceramic/1206	35V	Input CAP	
С3	0.1µF	X5R/X7R, Ceramic/0603	50V	Input CAP	Würth PART 885 012 206 095
C4	100pF	0603	100V	Feedback CAP	Würth PART 885 012 206 102
C5	0.1µF	X5R/X7R,	50V	Bootstrap CAP	Würth PART



		Ceramic/0603			885 012 206 095
C6 & C7	22µF	X5R/X7R, Ceramic/1206	25V	Output CAP	
L1	10μΗ	6060	5.0A	Inductor	Würth PART 744 393 461 00
R1	30K	0603	1%	Valtage set DEC*	
R3	157K	0603	1%	Voltage set RES*	
R4	0	0603	1%	Bootstrap RES	
U1		AP63201WU		TSOT26	Diodes Incorporated

^{*}Note: The present value of R3/R1 are based on Vout=5V

TYPICAL PERFORMANCE CHARACTERISTICS

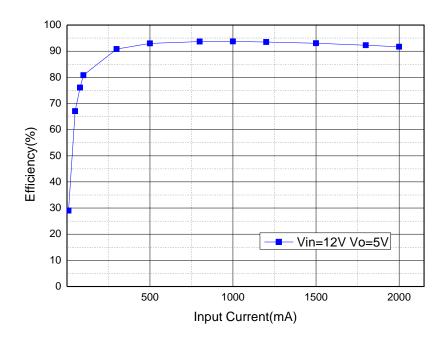
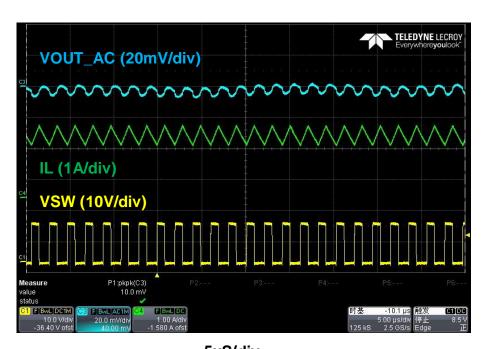


Figure 4. Efficiency for VIN=12V, VOUT= 5.0V





5µS/div

Figure 5. Output Ripple for VIN=12V, VOUT=5.0V, IOUT=2A

AP63201WU-EVM



32V, 2A, Synchronous DC-DC Buck Converter With Enhanced EMI Reduction

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